JOCDA3AB-W8

Rev.A.1.0

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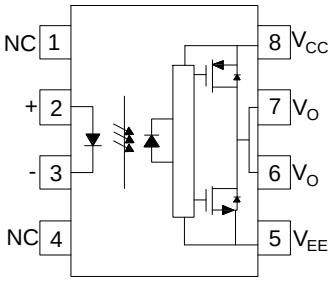
The products are gate driver opto-couplers in a plastic WSOP8 package. The device consists of an infrared LED optically coupled to an integrated high-gain, high-speed photodetector IC chip. It provides guaranteed performance and specifications at temperature up to 110 . It is physically smaller and compliant with international safety standards for reinforced insulation. It thus provides a smaller footprint solution for applications that require safety standard certification. An internal noise shield provides a guaranteed common-mode transient immunity of ±35 kV/μs. It is ideal for small class IGBT and power MOSFET gate drive. The products are widely used in industrial inverters, IGBT gate drivers, MOSFET gate drivers, induction cooktop and home appliances.



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High isolation 7500 VRMS
Buffer logic type
Operating temperature range -40°C to 110°C
REACH & RoHS compliance
HBM: H3A; MM: M4; CDM: C3
CQC approved
VDE approved
UL approved

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LED	V_{CC}-V_{EE} (Positive Going)	V_{CC}-V_{EE} (Negative Going)	Output
OFF	0-30V	0-30V	Low
ON	0-12.1V	0-11.1V	Low
ON	12.1V-13.5V	11.1V-12.4V	TRANSITION
ON	13.5V-30V	12.4V-30V	HIGH

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Parameter		Symbol	Value	Unit
LED	Forward Current	I_F	50	mA
	Peak Forward Current	I_{FP}	1	A
	Reverse Voltage	V_R	6	V
	Power Dissipation	P_D	100	mW
Detector	Output Voltage	V_O	35	V
	Supply Voltage	V_{CC}	35	V
	Power Dissipation	P_C	400	mW
Isolation Voltage		V_{iso}	7500	Vrms
Operating Temperature		T_{opr}	-40~110	
Junction Temperature		T_j	125	
Storage Temperature		T_{stg}	-55~125	
Total Power Dissipation		P_{tot}	500	mW
Soldering Temperature		T_{sol}	260	

bh¢9M: 100μs pulse, 100Hz frequency
bh¢9H: AC for 1minute, R.H.=40~60%

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Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit
Input	Forward Voltage	V_F	I_F=10mA	-	1.35	1.6	V
	Reverse Current	I_R	V_R=6V	-	-	1	μA
	Terminal Capacitance	C_t	V=0,f=1MHz	-	60	-	pF
Output	Peak High-level Output Current	I_{OPH}	V_O=V_{CC}-4V, Pulse width≤50μs	-1	-	-	A
			V_O=V_{CC}-15V, Pulse width≤10μs	-	-	-	A
	Peak Low-level Output Current	I_{OPL}	V_O=V_{EE}+2.5V, Pulse width≤50μs	1	-	-	A
			V_O=V_{EE}				

	High Level Output Voltage	V_{OH}	I_F=5mA, V_{CC}=10V, I_O=-100mA	6	8.4	-	V
	Low Level Output Voltage	V_{OL}	V_F=0.8V, V_{CC}=10V, I_O=100mA	-	0.3	1	V
	Threshold Input Current	I_{FLH}	V_{CC}=15V, V_O 1V	-	1.2	5	mA
	Threshold Input Voltage	V_{FHL}	V_{CC}=15V, V_O 1V	0.8	-	-	V
	Supply Voltage	V_{CC}	-	15	-	30	V
	UVLO Threshold	VUVLO+	V_O 5V, I_F=10mA	12.1	12.8	13.5	V
		VUVLO-	V_O 5V, I_F=10mA	11.1	11.8	12.4	V

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Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit

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Common Mode Transient Immunity at Low Level Output	$\|CM_L\|$	I_F=0mA V_{CC}=30V, T_a=25 , V_O(max)=1V V_{CM}=1000Vpp	±		-	kV/μs

All Typical values at T_a=25

b2ůŜм: Input signal (f=25kHz,duty=50%, tr=tf=5ns or less). C_L is less than 15 pF which includes probe and stray wiring capacitance.

b2ůŜн: CM_H is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic high state (VO 26V).

b2ůŜo: CML is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic low state (VO 1V).

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Characteristics	Symbol	Min.	Typ.	Max.	Unit
Input On-state Current	$I_{F(ON)}$	6.5	-	10	mA
Input Off-state Voltage	$V_{F(OFF)}$	0	-	0.8	V
Supply Voltage	V_{CC}	15	-	30	V
Operating Frequency	f	-	-	25	kHz

b2Ɀм TШ r Ȅ d̬ ǚ op Ȅ ϰ Mcon id d̬ caŋ giv Ȅ as Md Ȅ in ꟻ p Ȅ of 8 M d Ȅ M ĔanŌ M valu Ş WШ M iŌ M a Ą sys ǜ Ā 2 g Ą M 8 M Ą 2 Mľ =2 ş dĔ asШ M = ş b η M z d Ȅ d.

b2Ɀн AcŔr = M c = Ɫc ľ M ľ VĀ)M b d̬ con Ą n τ GN b ȄM sĦ 8 M gain8in Ȅ ş ofşa M ᴺ p b p ł y. TШ ssoul Ą ş aM η M η 4M

b2Ɀα TШ Ō ş fall 8 s of 8 M ons 8 n 0.5 μs.M u ľ

b2Ɀπ l ľ ϰ d̬ r ľ ng ľ Aop d̬ of ľ ϰ d̬) fbr ľ ϰ Ady vol η = g d̬6 τ V iŌ M ľ ľ in ꟻ = M M ꟻ ş d. t b η M r η M ş Ō r η

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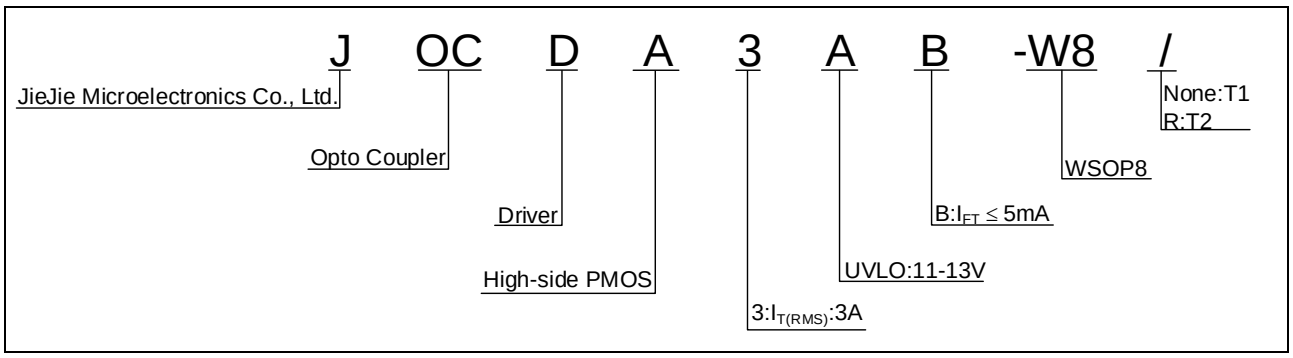

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None/R	1200 Units/Reel

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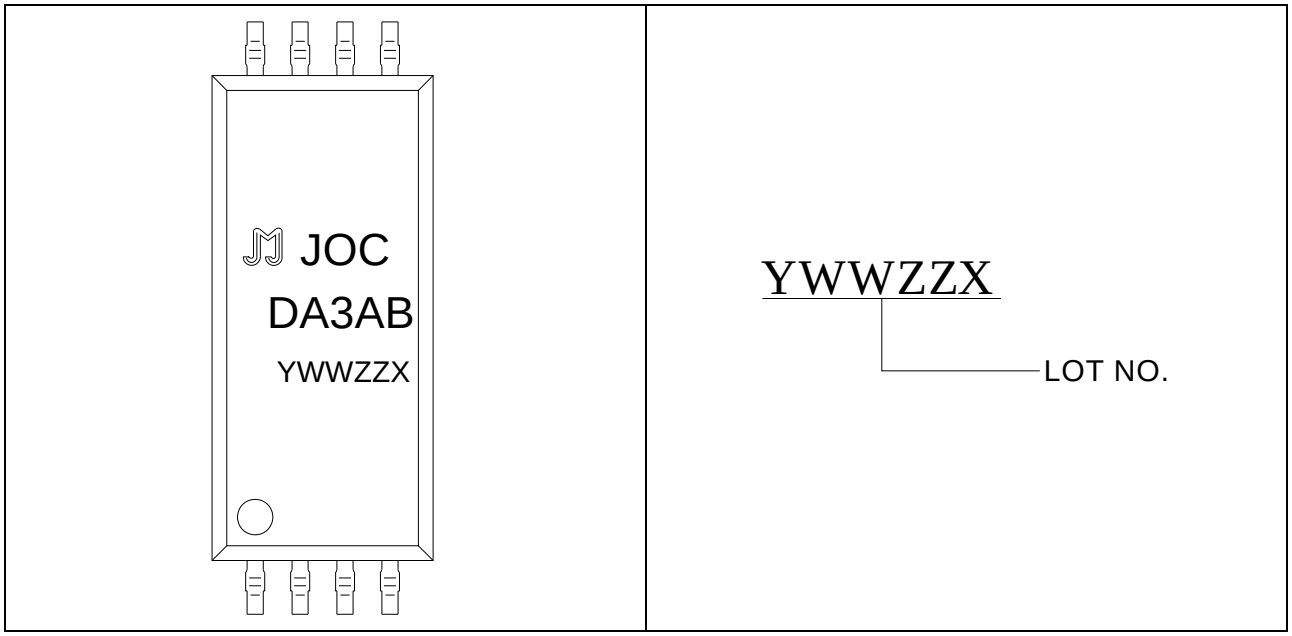

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FIG.1: Forward Current vs. Forward Voltage

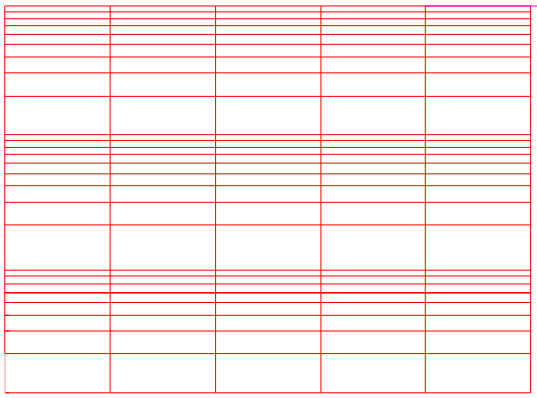

FIG.2: Max. Allowable LED Forward Current vs. Ambient Temperature

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Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	13.50		13.70	0.531		0.539
B	6.15		6.35	0.242		0.250
C	0.10		0.30	0.004		0.012
D	3.50		3.70	0.138		0.146
E	14.71		15.31	0.579		0.603
F	0.52		1.02	0.020		0.040
G	16.36		16.86	0.644		0.664
H	0.10		0.40	0.004		0.016
I	3.65		3.95 0.60	0.144		0.156B1.02
J	0.307		0.607	0.012		0.024
K						

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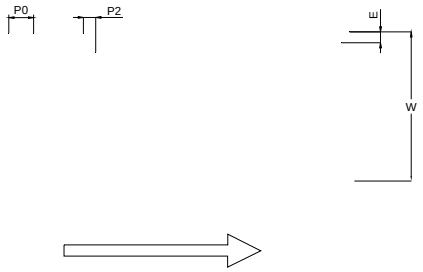

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Note:

1. Reflow soldering is recommended at the temperatures and times shown, no more than three times.

2. Avoid direct contact between the epoxy body and any tools or surfaces exceeding its maximum storage temperature.

3. Application of pressure on the epoxy body is prohibited at elevated temperatures. In spt ' on T T φ ts u